## 504804810 03/05/2018

# PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1 Stylesheet Version v1.2 EPAS ID: PAT4851542

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

#### **CONVEYING PARTY DATA**

Name	Execution Date
FEI ZHOU	03/05/2018

### **RECEIVING PARTY DATA**

Name:	SEMICONDUCTOR MANUFACTURING INTERNATIONAL (SHANGHAI) CORPORATION	
Street Address:	dress: 18 ZHANGJIANG ROAD, PUDONG NEW AREA	
City:	SHANGHAI	
State/Country:	CHINA	
Name:	SEMICONDUCTOR MANUFACTURING INTERNATIONAL (BEIJING) CORPORATION	
Street Address:	NO. 18 WEN CHANG RD., ECONOMIC-TECHNOLOGICAL DEVELOPMENT AREA, DAXING DISTRICT	
City:	BEIJING	
State/Country:	CHINA	

#### **PROPERTY NUMBERS Total: 1**

Property Type	Number		
Application Number:	15912218		

#### **CORRESPONDENCE DATA**

Fax Number:

Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.

**Phone:** 571-379-9468

Email: uspto@anovalaw.com

Correspondent Name: ANOVA LAW GROUP C/O SMIC

Address Line 1: 21495 RIDGETOP CIRCLE

Address Line 2: SUITE 300

Address Line 4: STERLING, VIRGINIA 20166

ATTORNEY DOCKET NUMBER:	00158.0494.00US
NAME OF SUBMITTER:	WENDY LIN
SIGNATURE:	/Wendy Lin/
DATE SIGNED:	03/05/2018

PATENT 504804810 REEL: 045110 FRAME: 0004

# **Total Attachments: 2**

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PATENT REEL: 045110 FRAME: 0005

# ASSIGNMENT AND DECLARATION

WHEREAS I/We, the below named inventor(s) (hereinafter referred to as Assignor(s)) have made an invention entitled:

FIN FIELD EFFECT TRANSISTOR AND FABRICATION METHOD THEREOF
for which I/We executed an application for United States Letters Patent concurrently herewith or filed an application for United States Letters Patent on(Application No,); and
WHEREAS, Semiconductor Manufacturing International (Shanghai) Corporation, a corporation of P. R. China whose post office address is 18 Zhangliang Road, Pudong New Area, Shanghai, China 201203, and Semiconductor Manufacturing International (Beijing) Corporation, a corporation of P. R. China whose post office address is No. 18, Wen Chang Rd. Economic-Technological Development Area Daxing District, Beijing, China,100716 (hereinafter referred to as Assignee), is desirous of securing the entire right, title, and interest in and to this invention in all countries throughout the world, and in and to the application for United States Letters Patent on this invention and the Letters Patent to be issued upon this application;
NOW THEREFORE, be it known that, for good and valuable consideration the receipt of which from Assignee is hereby acknowledged, I/We, as Assignor(s), have sold, assigned, transferred, and set over, and do hereby sell, assign, transfer, and set over unto the Assignee, its lawful successors and assigns, my/our entire right, title, and interest in and to this invention, provisional Application No
filed(if any), and this application, and all divisions, substitutions, continuations, and continuations-in-part thereof, and all Letters Patent of the United States which may be granted thereon, and all reissues thereof, and all rights to claim priority on the basis of the above provisional application (if any), as well as all rights to claim priority on the basis of this application, and all applications for Letters Patent which may hereafter be filed for this invention in any foreign country and all Letters Patent which may be granted on this invention in any foreign country, and all extensions, renewals, and reissues thereof, and I/We hereby authorize and request the Commissioner of Patents and Trademarks of the United States and any official of any foreign country whose duty it is to issue patents on applications as described above, to issue all Letters Patent for this invention to Assignee, its successors and assigns, in accordance with the terms of this Assignment;
AND, I/WE HEREBY covenant that I/We have the full right to convey the interest assigned by this Assignment, and I/We have not executed and will not execute any agreement in conflict with this Assignment;
AND, I/WE HEREBY further covenant and agree that I/We will, without further consideration, communicate with Assignee, its successors and assigns, any facts known to me/us respecting this invention, and testify in any legal proceeding, sign all lawful papers when called upon to do so, execute and deliver any and all papers that may be necessary or desirable to perfect the title to this invention in said Assignee, its successors or assigns, execute all divisional, continuation, and reissue applications, make all rightful paths and generally do everything possible to aid Assignee, its successors and assigns, to obtain and enforce proper patent protection for this invention in the United States and any foreign country, it being understood that any expense incident to the execution of such papers shall be borne by the Assignee, its successors and assigns.
AND, I/WE HEREBY authorize and request the attorneys I/we have empowered in the Declaration and Power of Attorney in this application, to insert here in parentheses (Application No filed) the filing date and application number of said application when known.

**RECORDED: 03/05/2018** 

### SMIC 2016-01006-SH-US Anova Law Group, PLLC 00158.0494.00US

F	Further, as a below named inventor, I hereby declare that:						
internatio	This declaration is directed to the application attached hereto or United States application or PC nternational application numberfiled onfiled onfiled process of the application is as identified above or by the attorney docket						
number s	If the application is not altached hereto, the application is as identified above or by the attorney docket number as set forth above and/or the following.						
٦	The above-identified application was made or authorized to be made by me.						
l applicatio		ne original inventor or an or	iginal joint inven	tor of a claimed invention in the			
claims.	I have reviewed and understand the contents of the above-identified application, including the claims.						
I acknowledge the duty to disclose information which is material to patentability as defined in Title 37,Code of Federal Regulations § 1,56, including for continuation-in-part applications, material information which became available between the filing data of the prior application and the national or PCT International filing date of the continuation-in-part application.							
		ge that any willful false stat imprisonment of not more t		his declaration is punishable under s, or both.			
IN TESTIMONY WHEREOF, I/We have hereunto set our hands.							
	Inventor 1 Legal Name:	Fei ZHOU					
	Signature:	Forzhu	Date:	63/05			
accompar	application data shee ny this form or must h mal inventors.	t (PTO/SB/14 or equivalent), i ave been previously filed. Ch	ncluding naming t eck the box below	ne entire inventive entity, must and complete the attached page(s) to			
Addit	ional inventors are be	eing named on the supplen	nental sheet(s) atta	ached hereto.			